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<u>Fairchild Semiconductor</u> <u>MPSH34</u>

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Datasheet of MPSH34 - TRANS NPN 40V 0.05A TO-92 Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



MPSH34

NPN General Purpose Amplifier

- This device is designed for common-emitter low noise amplifier and mixer applications with collector currents in the 100mA to 20mA range to 300MHz, and low frequency drift common-base VHF oscillator applications with high output levels for driving FET mixers.
- · Sourced from process 47.
- See MPSH11 for characteristics.



1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	40	V
V _{EBO}	Emitter-Base Voltage	4.0	V
I _C	Collector current - Continuous	50	mA
T _J , T _{stg}	Junction and Storage Temperature	-55 ~ +150	°C

$\textbf{Electrical Characteristics} \ \, \textbf{T}_{a} \!\!=\!\! 25^{\circ} \textbf{C} \ \, \textbf{unless otherwise noted}$

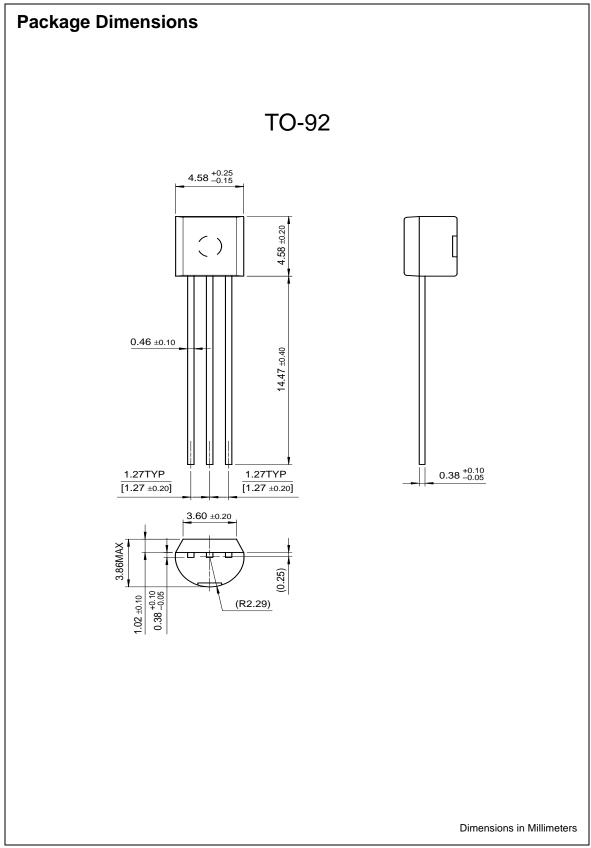
Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characte	eristics				
V _{(BR)CEO}	Collector-Emitter Sustaining Voltage *	$I_C = 1.0 \text{mA}, I_B = 0$	40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 100\mu A, I_E = 0$	40		
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10\mu A, I_C = 0$	4.0		VV
I _{CBO}	Collector Cutoff Current	$V_{CB} = 30V, I_{E} = 0$		50	nA
On Characte	eristics				•
h _{FE}	DC Current Gain	$V_{CE} = 2.0V, I_{C} = 20mA$ $V_{CE} = 15V, I_{C} = 7.0mA$	15 40		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 7.0mA, I _B = 2.0mA		0.5	V
V _{BE(on)}	Base-Emitter On Voltage	V _{CE} = 15V, I _C = 7.0mA		0.95	V
	I Characteristics				•
f _T	Current Gain Bandwidth Product	I _C =15mA, V _{CE} = 15V, f = 100MHz	500		MHz
C _{cb}	Collector-Base Capacitance	$V_{CB} = 10V, I_{E} = 0, f = 1.0MHz$		0.32	pF

Thermal Characteristics T_A=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation	625	mW
_	Derate above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W







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